## NSN 5961-00-407-2535

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View Online at https://aerobasegroup.com/nsn/5961-00-407-2535 **Inclosure Material:** Metal **Overall Length:** 0.283 inches **Overall Diameter:** 0.355 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.375 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 collector to emitter reverse voltage, with base short-circuited to emitter and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 100.00 milliamperes source cutoff current and 700.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 40.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 pin Shelf Life:

Demilitarization: No

**Unit Of Measure:** 

N/a

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